TVS Diodes Surface Mount - 400W > SMAJ-E Series

SMAJ-E Series







OBSOLETE DATE: 08/21/2020 PCN/ECN# 4135 REPLACED BY: SMAJ Series



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Peak Pulse Power Dissipation at T_A =25°C by 10/1000 μ s Waveform (Fig.2)(Note 1), (Note 2)	P _{PPM}	400	W
Power Dissipation on Infinite Heat Sink at T_L =50°C	P _D	3.3	W
Peak Forward Surge Current, 8.3ms Single Half Sine Wave (Note 3)	I _{FSM}	60	А
Maximum Instantaneous Forward Voltage at 25A for Unidirectional Only	V _F	3.5	V
Operating Temperature Range	T _J	-65 to 150	°C
Storage Temperature Range	T _{stg}	-65 to 175	°C
Typical Thermal Resistance Junction to Lead	R _{eJL}	30	°C/W
Typical Thermal Resistance Junction to Ambient	R _{eja}	120	°C/W

Notes:

- 1. Non-repetitive current pulse, per Fig.4 and derated above T_J (initial) =25°C per Fig. 3.
- 2. Mounted on 5.0x5.0mm copper pad to each terminal.
- 3. Measured on 8.3ms single half sine wave or equivalent square wave for unidirectional device only.

Description

The SMAJ-E series is designed specifically to protect sensitive electronic equipment from voltage transients induced by lightning and other transient voltage events.

Features

- Excellent clamping capability
- For surface mounted applications to optimize board space
- Low profile package
- Typical failure mode is short from over-specified voltage or current
- Whisker test is conducted based on JEDEC JESD201A per its table 4a and 4c
- IEC 61000-4-2 ESD 30kV(Air), 30kV (Contact)
- EFT protection of data lines in accordance with IEC 61000-4-4
- Built-in strain relief
- 400W Peak pulse power capability at 10/1000µs waveform, repetition rate (duty cycle): 0.01%
- Fast response time: typically less than 1.0ps from 0 Volts to $V_{\rm BR}$ min

- Glass passivated junction
- Low inductance
- High temperature to reflow soldering guaranteed: 260°C/40sec
- V_{BB} @ T_J= V_{BB}@25°C $\times (1 + \alpha T \times (T_1 - 25))$ (a T:Temperature Coefficient, typical value is 0.1%)
- EPI silicon technology
- Meet MSL level1, per J-STD-020C, LF maximun peak of 260°C
- Matte tin lead-free Plated
- Halogen free and RoHS compliant
- Pb-free E3 means 2nd level interconnect is Pb-free and the terminal finish material is tin(Sn) (IPC/JEDEC J-STD-609A.01)

Functional Diagram



Applications

TVS devices are ideal for the protection of I/O Interfaces, V_{cc} bus and other vulnerable circuits used in Telecom, Computer, Industrial and Consumer electronic applications.

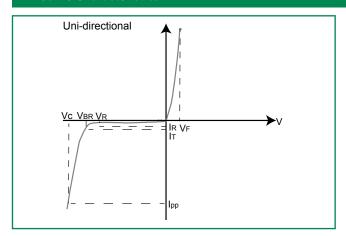
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Electrical Characteristics (T_A=25°C unless otherwise noted)

Part Number (Uni)	Marking	Reverse Stand off Voltage V _R	Voltag	down ge V _{BR} s) @ I _T	Test Current I _T	Maximum Clamping Voltage V _c @	Maximum Peak Pulse Current I _{pp}	Maximum Reverse Leakage I _R @ V _R
(31)		(Volts)	MIN	MAX	(mA)	(V)	(A)	(μA)
SMAJ300A-E	XE	300	335.0	371.0	1	486.0	0.80	1
SMAJ350A-E	XG	350	391.0	432.0	1	567.0	0.70	1
SMAJ400A-E*	XK	400	447.0	494.0	1	648.0	0.60	1
SMAJ450A-E*	XM	440	492.0	543.0	1	713.0	0.60	1
SMAJ500A-E*	XN	500	558.0	618.0	1	810.0	0.50	1
SMAJ550A-E*	XP	550	614.0	680.0	1	891.0	0.46	1
SMAJ600A-E*	XR	600	670.0	741.0	1	971.0	0.42	1
SMAJ650A-E*	XS	650	726.0	803.0	1	1052.0	0.39	1
SMAJ700A-E*	XT	700	782.0	865.0	1	1133.0	0.36	1
SMAJ750A-E*	XU	750	837.0	927.0	1	1213.0	0.33	1
SMAJ850A-E*	XV	850	950.0	1050.0	1	1365.0	0.30	1

Note: for parts with * are still under development

I-V Curve Characteristics



- P_{PPM} Peak Pulse Power Dissipation Max power dissipation
- $\mathbf{V}_{_{\!R}}$ Stand-off Voltage -- Maximum voltage that can be applied to the TVS without operation
- V_{BR} Breakdown Voltage Maximum voltage that flows though the TVS at a specified test current (I,)
- V_c Clamping Voltage Peak voltage measured across the TVS at a specified Ippm (peak impulse current)
- $I_{\scriptscriptstyle R}$ Reverse Leakage Current -- Current measured at $V_{\scriptscriptstyle R}$
- V, Forward Voltage Drop for Uni-directional



Ratings and Characteristic Curves (T_A=25°C unless otherwise noted)

Figure 1 - TVS Transients Clamping Waveform

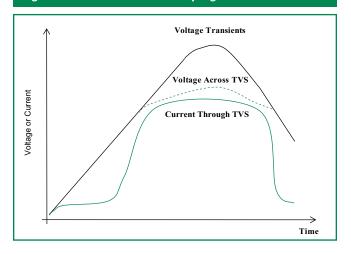


Figure 2 - Peak Pulse Power Rating Curve

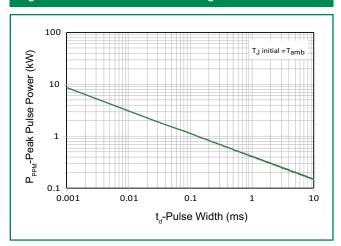


Figure 3 - Peak Pulse Power Derating Curve

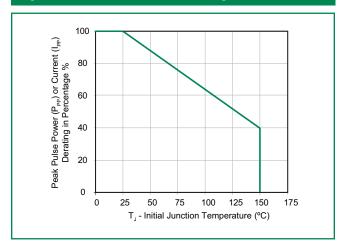


Figure 4 - Pulse Waveform

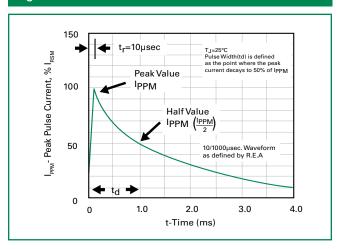


Figure 5 - Typical Junction Capacitance

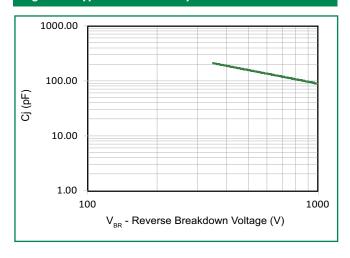


Figure 6 - Typical Transient Thermal Impedance

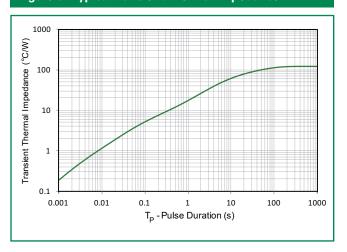




Figure 7 - Maximum Non-Repetitive Forward Surge Current Uni-Directional Only

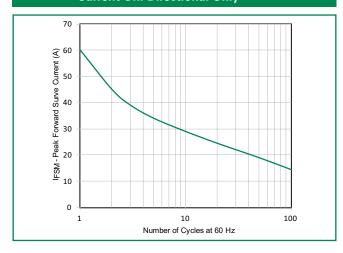
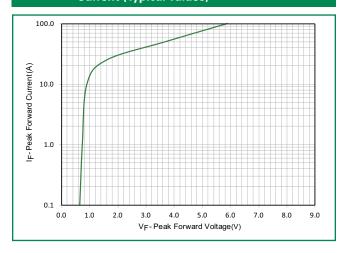
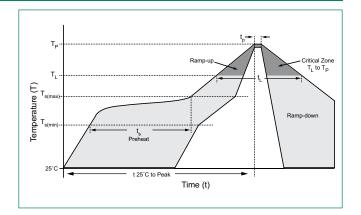


Figure 8 - Peak Forward Voltage Drop vs Peak Forward Current (Typical Values)



Soldering Parameters

Reflow Co	ndition	Lead-free assembly	
	-Temperature Min (T _{s(min)})	150°C	
Pre Heat	-Temperature Max (T _{s(max)})	200°C	
	-Time (min to max) (t _s)	60 – 180 secs	
Average ra	mp up rate (Liquidus Temp (T _A)	3°C/second max	
T _{S(max)} to T _A	- Ramp-up Rate	3°C/second max	
Reflow	-Temperature (T _A) (Liquidus)	217°C	
nellow	-Time (min to max) (t _s)	60 – 150 seconds	
Peak Temp	erature (T _P)	260 ^{+0/-5} °C	
Time withi	n 5°C of actual peak re (t _p)	20 - 40 seconds	
Ramp-dow	n Rate	6°C/second max	
Time 25°C	to peak Temperature (T _P)	8 minutes Max.	
Do not exc	ceed	260°C	



Physical Specifications

Weight	0.002 ounce, 0.061 gram
Case	JEDEC DO-214AC Molded Plastic over glass passivated junction
Polarity	Color band denotes cathode except Bipolar
Terminal	Matte Tin-plated leads, Solderable per JESD22-B102

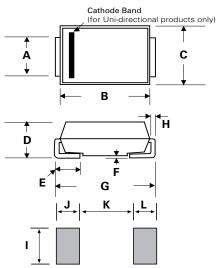
Environmental Specifications

High Temp. Storage	JESD22-A103
нткв	JESD22-A108
Temperature Cycling	JESD22-A104
MSL	JEDEC-J-STD-020, Level 1
H3TRB	JESD22-A101
RSH	JESD22-A111



Dimensions

DO-214AC (SMA)

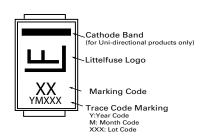


Dimensions	Incl	hes	Millimeters		
Dimensions	Min	Max	Min	Max	
А	0.049	0.065	1.250	1.650	
В	0.157	0.181	3.990	4.600	
С	0.095	0.110	2.400	2.790	
D	0.075	0.090	1.900	2.290	
E	0.030	0.060	0.780	1.520	
F	-	0.008	-	0.203	
G	0.189	0.208	4.800	5.280	
Н	0.006	0.012	0.152	0.305	
I	0.070	-	1.800	-	
J	0.082	-	2.100	-	
K	-	0.090	-	2.300	
L	0.082	-	2.100	-	

Part Numbering System

SMAJ XXX A-E EPI SILICON TECHNOLOGY 5% V_{BR} VOLTAGE TOLERANCE V_R VOLTAGE

Part Marking System



Packaging

Part number	Component Package	Quantity	Packaging Option	Packaging Specification
SMAJxxxA-E	DO-214AC	5000	Tape & Reel - 12mm tape/13" reel	EIA STD RS-481

Tape and Reel Specification

